## MC74VHC1G09E

## 2-Input AND Gate with Open Drain Output

The MC74VHC1G09E is an advanced high speed CMOS 2-input AND gate with open drain output fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The internal circuit is composed of three stages, including an open drain output which provides the capability to set output switching level. This allows the MC74VHC1G09E to be used to interface 5 V circuits to circuits of any voltage between $\mathrm{V}_{\mathrm{CC}}$ and 5.5 V using an external resistor and power supply.

The MC74VHC1G09E input structure provides protection when voltages up to 5.5 V are applied, regardless of the supply voltage.

## Features

- High Speed: $\mathrm{t}_{\mathrm{PD}}=4.3 \mathrm{~ns}$ (Typ) at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$
- Low Internal Power Dissipation: $\mathrm{I}_{\mathrm{CC}}=1 \mu \mathrm{~A}(\mathrm{Max})$ at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- Power Down Protection Provided on Inputs
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FETs $=62$; Equivalent Gates $=16$
- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant


Figure 1. Pinout (Top View)


Figure 2. Logic Symbol

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MARKING DIAGRAMS

$$
\begin{array}{ll}
\text { VX }=\text { Device Code } \\
\text { M } & =\text { Date Code }
\end{array}
$$


(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

| PIN ASSIGNMENT |  |
| :---: | :---: |
| 1 | IN B |
| 2 | IN A |
| 3 | GND |
| 4 | OUT Y |
| 5 | V CC |

FUNCTION TABLE

| Inputs |  | Output |
| :---: | :---: | :---: |
| A | B | Y |
| L | L | L |
| L | H | L |
| H | L | L |
| H | H | Z |

ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MC74VHC1G09E

MAXIMUM RATINGS

| Symbol | Characteristics | Value | Unit |
| :---: | :---: | :---: | :---: |
| $V_{\text {CC }}$ | DC Supply Voltage | -0.5 to +6.5 | V |
| $\mathrm{V}_{\text {IN }}$ | DC Input Voltage | -0.5 to +6.5 | V |
| $\mathrm{V}_{\text {OUT }}$ | DC Output Voltage | -0.5 to +6.5 | V |
| IIK | Input Diode Current | -20 | mA |
| lok | Output Diode Current | +20 | mA |
| Iout | DC Output Current, per Pin | +25 | mA |
| ICC | DC Supply Current, $\mathrm{V}_{\text {CC }}$ and GND | +50 | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power dissipation in still air | 200 | mW |
| $\theta_{\mathrm{JA}}$ | Thermal resistance | 333 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| TL | Lead temperature, 1 mm from case for 10 s | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction temperature under bias | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| MSL | Moisture Sensitivity | Level 1 |  |
| $\mathrm{F}_{\mathrm{R}}$ | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in |  |
| $\mathrm{V}_{\mathrm{ESD}}$ | ESD Withstand Voltage $\begin{array}{r}\text { Human Body Model (Note 1) } \\ \text { Charged Device Model (Note 2) }\end{array}$ | $\begin{aligned} & 4000 \\ & 1000 \end{aligned}$ | V |
| ILatchup | Latchup Performance Above $\mathrm{V}_{\mathrm{CC}}$ and Below GND at $125^{\circ} \mathrm{C}$ (Note 3) | $\pm 100$ | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Tested to EIA/JESD22-A114-A
2. Tested to JESD22-C101-A
3. Tested to EIA/JESD78

## RECOMMENDED OPERATING CONDITIONS

| Symbol | Characteristics | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage | 2.0 | 5.5 | V |
| $\mathrm{~V}_{\mathrm{IN}}$ | DC Input Voltage | 0.0 | 5.5 | V |
| $\mathrm{~V}_{\text {OUT }}$ | DC Output Voltage | 0.0 | 7.0 | V |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating Temperature Range | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | Input Rise and Fall Time | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ | 0 | 10 |
|  | $\mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | $\mathrm{~ns} / \mathrm{V}$ |  |  |
|  |  | 0 | 5 |  |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | $\mathrm{V}_{\mathrm{Cc}}$ <br> (V) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ |  | $-55 \leq \mathrm{T}_{\text {A }} \leq 125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Minimum High-Level Input Voltage |  | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 4.5 \\ & 5.5 \end{aligned}$ | $\begin{gathered} 1.5 \\ 2.1 \\ 3.15 \\ 3.85 \end{gathered}$ |  |  | $\begin{gathered} 1.5 \\ 2.1 \\ 3.15 \\ 3.85 \end{gathered}$ |  | $\begin{aligned} & 1.5 \\ & 2.1 \\ & 3.15 \\ & 3.85 \end{aligned}$ |  | V |
| $\mathrm{V}_{\text {IL }}$ | Maximum Low-Level Input Voltage |  | 2.0 3.0 4.5 5.5 |  |  | $\begin{gathered} \hline 0.5 \\ 0.9 \\ 1.35 \\ 1.65 \end{gathered}$ |  | $\begin{gathered} \hline 0.5 \\ 0.9 \\ 1.35 \\ 1.65 \end{gathered}$ |  | $\begin{aligned} & \hline 0.5 \\ & 0.9 \\ & 1.35 \\ & 1.65 \end{aligned}$ | V |
| $\mathrm{V}_{\mathrm{OL}}$ | Maximum Low-Level Output Voltage $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} \\ & \mathrm{I}_{\mathrm{OL}}=50 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 4.5 \end{aligned}$ |  | $\begin{aligned} & \hline 0.0 \\ & 0.0 \\ & 0.0 \end{aligned}$ | $\begin{aligned} & 0.1 \\ & 0.1 \\ & 0.1 \end{aligned}$ |  | $\begin{aligned} & \hline 0.1 \\ & 0.1 \\ & 0.1 \end{aligned}$ |  | $\begin{aligned} & \hline 0.1 \\ & 0.1 \\ & 0.1 \end{aligned}$ | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} \\ & \mathrm{I}_{\mathrm{OL}}=4 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA} \\ & \hline \end{aligned}$ | $\begin{aligned} & 3.0 \\ & 4.5 \end{aligned}$ |  |  | $\begin{aligned} & 0.36 \\ & 0.36 \end{aligned}$ |  | $\begin{aligned} & 0.44 \\ & 0.44 \end{aligned}$ |  | $\begin{aligned} & 0.52 \\ & 0.52 \\ & \hline \end{aligned}$ | V |
| 1 N | Maximum Input Leakage Current | $\mathrm{V}_{\mathrm{IN}}=5.5 \mathrm{~V}$ or GND | $\begin{aligned} & 0 \text { to } \\ & 5.5 \end{aligned}$ |  |  | $\pm 0.1$ |  | $\pm 1.0$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| ICC | Maximum Quiescent Supply Current | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {CC }}$ or GND | 5.5 |  |  | 1.0 |  | 20 |  | 40 | $\mu \mathrm{A}$ |
| IofF | Power Off-Output Leakage Current | $\begin{array}{\|l} \hline \mathrm{V}_{\text {OUT }}=5.5 \mathrm{~V} \\ \mathrm{~V}_{\text {IN }}=5.5 \mathrm{~V} \\ \hline \end{array}$ | 0 |  |  | 0.25 |  | 2.5 |  | 5 | $\mu \mathrm{A}$ |

AC ELECTRICAL CHARACTERISTICS $\operatorname{Input} t_{r}=t_{f}=3.0 \mathrm{~ns}$

| Symbol | Parameter | Test Conditions | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ |  | $-55 \leq \mathrm{T}_{\mathrm{A}} \leq 125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max | Min | Max | Min | Max |  |
| tpzL | Maximum Output Enable Time, Input $A$ or $B$ to $Y$ | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=3.3 \pm 0.3 & \mathrm{~V}_{\mathrm{L}}=15 \mathrm{pF} \\ \mathrm{R}_{\mathrm{L}}=1000 \Omega & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{array}$ |  | $\begin{aligned} & 6.2 \\ & 8.7 \end{aligned}$ | $\begin{gathered} \hline 8.8 \\ 12.3 \end{gathered}$ |  | $\begin{aligned} & 10.5 \\ & 14.0 \end{aligned}$ |  | $\begin{aligned} & 12.5 \\ & 16.5 \end{aligned}$ | ns |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=1000 \Omega \end{aligned} \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} .$ |  | $\begin{aligned} & \hline 4.3 \\ & 5.8 \end{aligned}$ | $\begin{aligned} & 5.9 \\ & 7.9 \end{aligned}$ |  | $\begin{aligned} & 7.0 \\ & 9.0 \end{aligned}$ |  | $\begin{gathered} 9.0 \\ 11.0 \end{gathered}$ |  |
| tplz | Maximum Output Disable Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=1000 \Omega \end{aligned}$ |  | 8.7 | 12.3 |  | 14.0 |  | 16.5 | ns |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=1000 \Omega \end{aligned}$ |  | 5.8 | 7.9 |  | 9.0 |  | 11.0 |  |
| $\mathrm{C}_{\text {IN }}$ | Maximum Input Capacitance |  |  | 6.0 | 10 |  | 10 |  | 10 | pF |


|  |  | Typical @ $\mathbf{2 5}{ }^{\circ} \mathbf{C}, \mathbf{V} \mathbf{C C}=5.0 \mathbf{V}$ |  |
| :--- | :--- | :---: | :---: |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance (Note 4) | 18 | pF |

4. $\mathrm{C}_{\mathrm{PD}}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $\mathrm{I}_{\mathrm{CC}(\mathrm{OPR})}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}}$. $\mathrm{C}_{\mathrm{PD}}$ is used to determine the no-load dynamic power consumption; $\mathrm{P}_{\mathrm{D}}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}}{ }^{2} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} \bullet \mathrm{V}_{\mathrm{CC}}$.


Figure 3. Output Voltage Mismatch Application


Figure 4. Switching Waveforms

$C_{L}=50 \mathrm{pF}$ equivalent (Includes jig and probe capacitance)
$R_{L}=1000 \Omega$ or equivalent
$\mathrm{R}_{\mathrm{T}}=\mathrm{Z}_{\text {OUT }}$ of pulse generator (typically $50 \Omega$ )
Figure 5. Test Circuit


Figure 6. Complex Boolean Functions


Figure 7. LED Driver


Figure 8. GTL Driver

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| MC74VHC1G09EDFT2G | SC70-5 / SC-88A / SOT-353 <br> $($ Pb-Free $)$ | $3000 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MC74VHC1G09E

## PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353)
CASE 419A-02
ISSUE L


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
2. CONTROLLING DIMENSION: INCH
3. 419A-01 OBSOLETE. NEW STANDARD

419A-01
$419 \mathrm{~A}-02$.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | INCHES |  | MILLIMETERS |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |  |  |
| A | 0.071 | 0.087 | 1.80 | 2.20 |  |  |
| B | 0.045 | 0.053 | 1.15 | 1.35 |  |  |
| C | 0.031 | 0.043 | 0.80 | 1.10 |  |  |
| D | 0.004 | 0.012 | 0.10 |  |  |  |
| G | 0.026 |  | BSC | 0.65 BSC |  |  |
| H | -- |  | 0.004 | --- |  |  |
| J | 0.004 | 0.010 | 0.10 |  |  |  |
| K | 0.004 | 0.012 | 0.10 |  |  |  |
| N | 0.008 |  | REF | 0.20 |  | REF |
| S | 0.079 |  | 0.087 | 2.00 |  | 2.20 |



SOLDERING FOOTPRINT*

*For additional information on our $\mathrm{Pb}-F r e e$ strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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NLX1G97MUTCG 74LS38 74LVC32ADTR2G MC74HCT20ADTR2G NLV17SZ00DFT2G NLV17SZ02DFT2G NLV74HC02ADR2G
74HC32S14-13 74LS133 74LVC1G32Z-7 M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7 NLV74HC08ADTR2G
NLV74HC14ADR2G NLV74HC20ADR2G NLX2G86MUTCG 5962-8973601DA 74LVC2G02HD4-7 NLU1G00AMUTCG
74LVC2G32RA3-7 74LVC2G00HD4-7 NL17SG02P5T5G 74LVC2G00HK3-7 74LVC2G86HK3-7 NLX1G99DMUTWG NLVVHC1G00DFT2G NLVHC1G08DFT2G NLV7SZ57DFT2G NLV74VHC04DTR2G NLV27WZ86USG NLV27WZ00USG

NLU1G86CMUTCG NLU1G08CMUTCG NL17SZ32P5T5G NL17SZ00P5T5G NL17SH02P5T5G 74AUP2G00RA3-7
NLV74HC02ADTR2G NLX1G332CMUTCG NL17SG86P5T5G NL17SZ05P5T5G NLV74VHC00DTR2G

